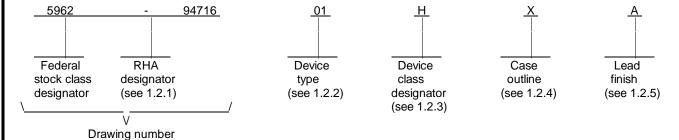
LTR								F	REVIS	IONS										
•		DESCRIPTION										DATE (YR-MO-DA)			APPROVED					
Α		Add device type 05, case outlines M, N, 4, 5, 6, 7, ar CAGE code 88379.						7, and	8. Add vendor 96-08-30) K. A. Cottongim								
REV SHEET																				
SHEET	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A	A		
SHEET REV SHEET	15	A 16	A 17	18	19	A 20	21	22	23	24	25	26	27	28	29	30	31	32		
SHEET REV SHEET REV STATU	15 IS			18 RE\	19 /	1	21 A	22 A	23 A	24 A	25 A	26 A	27 A	28 A	29 A	30 A	31 A	32 A	A 12	A
SHEET REV SHEET REV STATU OF SHEETS PMIC N/A	15 IS	16		18 RE\ SHE	19	20 BY	21	22	23	24	25 A 5	26 A 6	27 A 7	28 A 8	29 A 9	30 A 10	31 A 11	32 A 12	13	
SHEET REV SHEET REV STATU OF SHEETS PMIC N/A STA MICRO	NDA OCIR	RD CUITIG	17	18 RE\ SHE PREI Stev CHE Mid	19 V EET PAREI CKED CKED Chael C	20 D BY uncan BY Jones	21 A 1	22 A	23 A	24 A 4	25 A 5	26 A 6 DEFEI C RCUI LE/PR	27 A 7 NSE S OLUM	28 A 8	29 A 9 -Y CE, OHIO	30 A 10 NTER 4321	31 A 11 COLU 16-500	32 A 12 JMBUS 0	13	14
SHEET REV SHEET REV STATU OF SHEETS PMIC N/A STA MICRO DRA THIS DRAWI FOR U	NDA OCIR AWIN NG IS A JSE BY A RTMEN NCIES (RD CUITIG VAILAI	17 F BLE	18 RE\ SHE PRE Stev CHE Mic	19 V EET PAREL e L. Du CKED Chael C ROVEI dall A.	20 D BY uncan BY D BY Cotton	21 A 1	22 A 2	23 A	A A 4 MIC ERA 128	25 A 5 I ROCI ASABI K x 3	26 A 6 DEFEI C RCUI LE/PR 32-BIT CAG	A 7 NSE S COLUM	A 8 8 BUPPL IBUS, /BRIE AMM	29 A 9 -Y CE, OHIO	30 A 10 NTER 4321 SITAL REA	31 A 11 COLU 16-500	32 A 12 JMBUS 0	13 1EMO	14
SHEET REV SHEET REV STATU OF SHEETS PMIC N/A STA MICRO DRA THIS DRAWI FOR U DEPA AND AGE	NDA OCIR AWIN NG IS A JSE BY A RTMEN NCIES (NT OF I	RD CUITIG VAILAI	17 F BLE	18 RE\ SHE PREIStev CHE Mic	19 V EET PAREL PAR	20 D BY uncan BY D BY Cotton	21 A 1	22 A 2	23 A	A A 4 MIC ERA 128	25 A 5 I ROCI ASABI K x 3	26 A 6 DEFEI C RCUI LE/PR 32-BIT CAG	27 A 7 NSE S COLUM	A 8 8 BUPPL IBUS, /BRIE AMM	29 A 9 -Y CE, OHIO	30 A 10 NTER 4321 SITAL REA	31 A 11 COLU 16-500	32 A 12 JMBUS 0	13 1EMO	1

- 1. SCOPE
- 1.1 <u>Scope</u>. This drawing documents two product assurance classes, high reliability (device class H) and space application (device class K) and a choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of radiation hardness assurance levels are reflected in the PIN.
 - 1.2 PIN. The PIN shall be as shown in the following example:



- 1.2.1 <u>Radiation hardness assurance (RHA) designator</u>. Device classes H and K RHA marked devices shall meet the MIL-PRF-38534 specified RHA levels and shall be marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.
 - 1.2.2 <u>Device type(s)</u>. The device type(s) shall identify the circuit function as follows:

Generic number	Circuit function	Access Time
WF128K32-150HQ5, ACT-F128K32N-150	FLASH EPROM, 128K X 32-bit	150 ns
WF128K32-120HQ5, ACT-F128K32N-120	FLASH EPROM, 128K X 32-bit	120 ns
WF128K32-90HQ5, ACT-F128K32N-090	FLASH EPROM, 128K X 32-bit	90 ns
WF128K32-70HQ5, ACT-F128K32N-070	FLASH EPROM, 128K X 32-bit	70 ns
WF128K32-60HQ5	FLASH EPROM, 128K X 32-bit	60 ns
	WF128K32-150HQ5, ACT-F128K32N-150 WF128K32-120HQ5, ACT-F128K32N-120 WF128K32-90HQ5, ACT-F128K32N-090 WF128K32-70HQ5, ACT-F128K32N-070	WF128K32-150HQ5, ACT-F128K32N-150 FLASH EPROM, 128K X 32-bit WF128K32-90HQ5, ACT-F128K32N-090 FLASH EPROM, 128K X 32-bit WF128K32-70HQ5, ACT-F128K32N-070 FLASH EPROM, 128K X 32-bit FLASH EPROM, 128K X 32-bit FLASH EPROM, 128K X 32-bit

1.2.3 <u>Device class designator</u>. This device class designator shall be a single letter identifying the product assurance level as follows:

Device class

Device performance documentation

H or K

Certification and qualification to MIL-PRF-38534

1.2.4 <u>Case outline(s)</u>. The case outline(s) shall be as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
М	See figure 1	68	Ceramic, dual cavity, quad pack, lead formed
N	See figure 1	68	Ceramic, low profile, single cavity, quad pack, lead formed
S	See figure 1	66	Hex-in-line, single cavity, with standoffs
T	See figure 1	66	Hex-in-line, single cavity, without standoffs
U	See figure 1	66	Hex-in-line, single cavity, with standoffs
V	See figure 1	66	Hex-in-line, single cavity, without standoffs
W	See figure 1	66	Hex-in-line, single cavity, with standoffs
Χ	See figure 1	66	Hex-in-line, single cavity, without standoffs
Υ	See figure 1	66	Hex-in-line, single cavity, with standoffs
Z	See figure 1	66	Hex-in-line, single cavity, without standoffs
4	See figure 1	68	Cermic, single cavity, quad flat pack
5	See figure 1	66	1.075", hex-in-line, single cavity, with standoffs
6	See figure 1	66	1.075", hex-in-line, single cavity, with standoffs
7	See figure 1	66	1.075", hex-in-line, single cavity, with standoffs
8	See figure 1	66	1.075", hex-in-line, single cavity, with standoffs

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1.2.5 Lead finish. The lead finish shall be as specified in MIL-PRF-38534 for classes H and K.

1.3 Absolute maximum ratings. 1/

Supply voltage range (V _{CC}) <u>2</u> /	-2.0 V dc to +7.0 V dc
Signal Voltage range (any pin except A9) 2/	-2.0 V dc to +7.0 V dc
Power dissipation (PD)	1.1 W
Storage temperature range	-65° C to +150° C
Lead temperature (soldering, 10 seconds)	+300 °C
Data retention	10 years minimum
Endurance (write/erase cycles)	10,000 cycles minimum
A9 voltage for sector protect (V _{ID}) <u>3</u> /	-2.0 V dc to +14.0 V dc

1.4 Recommended operating conditions.

Supply voltage range (V _{CC})	+4.5 V dc to +5.5 V dc
Input low voltage range (V _{IL})	-0.5 V dc to +0.8 V dc
Input high voltage range (VIH)	+2.0 V dc to V _{CC} + 0.3 V dc
Case operating temperature range (T _C)	-55°C to +125°C
A9 Voltage for sector protect (V _{ID})	+11.5 V dc to +12.5 V dc

2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbook. The following specification, standards, and handbook form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those listed in the issue of the Department of Defense Index of Specifications and Standards (DoDISS) and supplement thereto, cited in the solitation.

SPECIFICATION

DEPARTMENT OF DEFENSE

MIL-PRF-38534 - Hybrid Microcircuits, General Specification for.

STANDARDS

DEPARTMENT OF DEFENSE

MIL-STD-883 - Test Methods and Procedures for Microelectronics. MIL-STD-973 - Configuration Management.

MIL-STD-1835 - Microcircuit Case Outlines.

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Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

Minimum DC voltage on input or I/O pins is -0.5 V dc. During voltage transitions, inputs may overshoot VSS to -2.0 V dc for periods of up to 20 ns. Maximum DC voltage on output and I/O pins is V_{CC} +0.5 V dc. During voltage transitions,outputs may overshoot to V_{CC} + 2.0 V dc for periods up to 20 ns.

Minimum DC input voltage on A9 pin is -0.5 V dc. During voltage transitions, A9 may overshoot V_{SS} to -2.0 V dc for periods up to 20 ns. Maximum DC input voltage on A9 is +13.5 V dc which may overshoot to +14.0 V dc forperiods up to 20 ns.

HANDBOOK

DEPARTMENT OF DEFENSE

MIL-HDBK-780 - Standard Microcircuit Drawings.

(Unless otherwise indicated, copies of the specification, standards, and handbook are available from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item performance requirements for device classes H and K shall be in accordance with MIL-PRF-38534 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38534 and herein.
 - 3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein and figure 1.
 - 3.2.2 <u>Terminal connections</u>. The terminal connections shall be as specified on figure 2.
 - 3.2.3 Truth table(s). The truth table(s) shall be as specified on figure 3.
 - 3.2.4 Logic diagram(s). The logic diagram(s) shall be as specified on figure 4, 5, and 6.
 - 3.2.5 Block diagram. The block diagram shall be as specified on figure 7.
 - 3.2.6 Output load circuit. The output load circuit shall be as specified on figure 8.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full specified operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are defined in table I.
- 3.5 <u>Programming procedure</u>. The programming procedure shall be as specified by the manufacturer and shall be available on request.
- 3.6 <u>Marking of Device(s)</u>. Marking of device(s) shall be in accordance with MIL-PRF-38534. The device shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's vendor similar PIN may also be marked as listed in QML-38534.

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- 3.7 <u>Data</u>. In addition to the general performance requirements of MIL-PRF-38534, the manufacturer of the device described herein shall maintain the electrical test data (variables format) from the initial quality conformance inspection group A lot sample, for each device type listed herein. Also, the data should include a summary of all parameters manually tested, and for those which, if any, are guaranteed. This data shall be maintained under document revision level control by the manufacturer and be made available to the preparing activity (DSCC-VA) upon request.
- 3.8 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to supply to this drawing. The certificate of compliance (original copy) submitted to DSCC-VA shall affirm that the manufacturer's product meets the performance requirements of MIL-PRF-38534 and herein.
- 3.9 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-PRF-38534 shall be provided with each lot of microcircuits delivered to this drawing.
- 3.10 Endurance. A reprogrammability test shall be completed as part of the vendors's reliability monitors. This reprogrammability test shall be done for the initial characterization and after any design process changes which may affect the reprogrammability of the device. The methods and procedures may be vendor specific, but shall guarantee the number of program/erase endurance cycles listed in section 1.3 herein over the full military temperature range. The vendors procedure shall be kept under document control and shall be made available upon request of the acquiring of preparing activity.
- 3.11 <u>Data retention</u>. A data retention stress test shall be completed as part of the vendor's reliability monitors. This test shall be done for initial characterization and after any design or process change which may affect data retention. The methods and procedures may be vendor specific, but shall guarantee the number of years listed in section 1.3 herein over the full military temperature range. The vendor's procedure shall be kept under document control and shall be made available upon request of the acquiring or preparing activity.

4	QUAL	ITY /	ASSU	RANCE	PRO\	/ISIONS

4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with MIL-PRF-38534 or as modified
in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or
function as described berein

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	TABLE I. Electrical perform	nance characte	eristics.			
Symbol	Conditions <u>1</u> / <u>2</u> / -55° C ≤ T _A ≤ +125° C	Group A subgroups	Device type	Lim	nits	Unit
	unless otherwise specified			Min	Max	
I	I	I	1	I	I	ı
ILI	$V_{CC} = 5.5 \text{ V dc}, V_{IN} = \text{GND}$ to V_{CC}	1,2,3	All		10	μΑ
l _{LO}	$V_{CC} = 5.5 \text{ V dc}, V_{IN} = \text{GND}$ to V_{CC}	1,2,3	All		10	μ Α
ICC1	CS = V _{IL} , OE = V _{IH} , V _{CC} = 5.5 V dc, f = 5 MHz	1,2,3	All		140	mA
I _{CC2}	CS = V _{IL} , OE = V _{IH} , V _{CC} = 5.5 V dc	1,2,3	All		200	mA
lCC3	V _{CC} = 5.5 V dc, CS = V _{IH} , f = 5 MHz	1,2,3	All		6.5	mA
V _{IL}		1,2,3	All		0.8	V
VIH		1,2,3	All	2.0		V
V _{OL}	V _{CC} = 4.5 V dc, I _{OL} = 12.0 mA	1,2,3	All		0.45	V
V _{OH1}	V _{CC} = 4.5 V dc, I _{OH} = -2.5 mA	1,2,3	All	0.85 x V _{CC}		V
V_{OH2} $V_{CC} = 4.5 \text{ V dc}, \ I_{OH} = -100 \ \mu\text{A}$		1,2,3	All	V _{CC} - 0.4Vdc		V
1		1	1	1	1	1
C _{OE}	V _{IN} = 0 V, f = 1.0 MHz, T _A = +25° C	4	All		50	pF
C _{AD}	V _{IN} = 0 V, f = 1.0 MHz, T _A = +25°C	4	All		50	pF
	ILI ILO ICC1 ICC2 ICC3 VIL VIH VOL VOH1 VOH2 3/ COE	Symbol Conditions $\frac{1}{2}$ / -55° C ≤ T _A ≤ +125° C unless otherwise specified ILI	Symbol Conditions 1/2/ -55° C ≤ T _A ≤ +125° C unless otherwise specified	1.55° C ≤ T _A ≤ +125° C unless otherwise specified 1.2,3 All	$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	Symbol Conditions 1/2/ -55°C ≤ TA ≤ +125°C unless otherwise specified Group A subgroups Device type Limits ILI VCC = 5.5 V dc, VIN = GND to VCC 1,2,3 All 10 ILO VCC = 5.5 V dc, VIN = GND to VCC 1,2,3 All 10 ICC1 CS = VIL, OE = VIH, VCC = 5.5 V dc, f = 5 MHz 1,2,3 All 140 ICC2 CS = VIL, OE = VIH, VCC = 5.5 V dc, CS = VIH, F = 5 MHz 1,2,3 All 200 ICC3 VCC = 5.5 V dc, CS = VIH, F = 5 MHz 1,2,3 All 0.8 VIL 1,2,3 All 2.0 VOL VCC = 4.5 V dc, IOL = 12.0 mA 1,2,3 All 0.45 VOH1 VCC = 4.5 V dc, IOH = -100 µA 1,2,3 All 0.85 x VCC COE VIN = 0 V, f = 1.0 MHz, TA = +25°C 4 All 50

See footnotes at end of table.

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Test	Symbol	Conditions $\underline{1}/\underline{2}/$ -55° C \leq T _A \leq +125° C unless otherwise specified	Group A subgroups	Device type	Lir	mits	Unit
		unless otherwise specified			Min	Max	
Dynamic Characteristics -	Continued	<u>.</u>	I	I			
CS capacitance <u>3</u> /	C _{CS}	V _{IN} = 0 V, f = 1.0 MHz, T _A = +25 °C	4	All		20	pF
— WE capacitance <u>3</u> /	C _{WE}	V _{IN} = 0 V, f = 1.0 MHz, T _A = +25 ° C Case outline 4,only		A.II		50	
			4	All		50	_ pF
		Remaining case outlines				20	
I/O0-I/O31 capacitance 3/	C _{I/O}	$V_{I/O} = 0 \text{ V, f} = 1.0 \text{ MHz}$ $T_A = +25 ^{\circ}\text{C}$	4	All		20	pF
Functional testing	1		1	1			
Functional tests Read cycle AC timing Cha	aracteristics	See 4.3.1c	7,8A,8B	All			
Read cycle time <u>3</u> /	^t RC	See figure 4	9,10,11	01 02 03 04 05	150 120 90 70 60		ns
Address access time	^t ACC	See figure 4	9,10,11	01 02 03 04 05		150 120 90 70 60	ns
Chip select access time	^t CE	See figure 4	9,10,11	01 02 03 04 05		150 120 90 70 60	ns
Output Enable to output valid	^t OE	See figure 4	9,10,11	01 02 03 04 05		55 50 40 35 30	ns
Chip Select to output high Z <u>3</u> /	^t DF	See figure 4	9,10,11	01 02 03 04,05		35 30 25 20	ns

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Test	Symbol Conditions $\underline{1}/\underline{2}/$ -55° C \leq T _A \leq +125° C	Group A subgroups	Device type	Lir	mits	Unit	
		unless otherwise specified		31 -	Min	Max	
Read cycle AC timing - C	Continued.				1		ı
OE high to output high Z <u>3</u> /	^t DF	See figure 4	9,10,11	01 02 03 04,05		35 30 25 20	ns
Output hold from address, CS or OE change, whichever is first 3/	[†] ОН	See figure 4	9,10,11	All	0		ns
Write cycle AC timing - V	Vrite/Erase/F	Program operations WE contro	lled.			-	1
Write cycle time 3/	twc	See figure 5	9,10,11	01 02 03 04 05	150 120 90 70 60		ns
Chip Select setup time	tcs	See figure 5	9,10,11	All	0		ns
Write Enable pulse width	tWP	See figure 5	9,10,11	01,02 03 04 05	50 45 35 30		ns
Address setup time	t _{AS}	See figure 5	9,10,11	All	0		ns
Data setup time	^t DS	See figure 5	9,10,11	01 02 03 04,05	50 50 45 30		ns
Data hold time	^t DH	See figure 5	9,10,11	All	0		ns
Address Hold time	^t AH	See figure 5	9,10,11	01,02 03,04, 05	50 45		ns

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Test	Symbol Conditions 1/2/	Group A	Device	Limits		Unit	
		-55° C ≤ T _A ≤ +125° C unless otherwise specified	subgroups	type	Min	Max	
Write cycle AC timing - W	/ rite/Erase/I	Program operations WE contro	lled - Continued	1.			
Write Enable pulse width high 3/	tWPH	See figure 5	9,10,11	All	20		ns
Read recovery before write 3/	^t GHWL	See figure 5	9,10,11	All	0		ns
Write cycle AC timing - W	/rite/Erase/I	Program Operations CS contro	lled.				
Write cycle time <u>3</u> /	tWC	See figure 6	9,10,11	01 02 03 04 05	150 120 90 70 60		ns
Write Enable setup time	t _{WS}	See figure 6	9,10,11	All	0		ns
Address setup time	t _{AS}	See figure 6	9,10,11	All	0		ns
Data setup time	t _{DS}	See figure 6	9,10,11	01 02 03 04,05	50 50 45 30		ns
Data hold time	^t DH	See figure 6	9,10,11	All	0		ns
Address hold time	^t AH	See figure 6	9,10,11	01,02 03,04, 05	50 45		ns
Chip Select pulse width See footnotes at end of ta	tCP	See figure 6	9,10,11	01 02 03 04 05	50 50 45 35 30		ns

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TABLE I. <u>Electrical performance characteristics</u> - Continued.									
Test	Symbol	Conditions <u>1</u> / <u>2</u> / -55° C ≤ T _A ≤ +125° C	Group A Devic subgroups type			Device type			Unit
		unless otherwise specified			Min	Max			
Write cycle AC timing - W	rite/Erase/F	Program Operations CS controlle	ed - Continued		1	I			
Chip Select pulse width high <u>3</u> /	^t CPH	See figure 6	9,10,11	All	20		ns		
Read recovery before write 3/	^t GHEL	See figure 6	9,10,11	All	0		ns		

- $\underline{1}/$ Unless otherwise specified, 4.5 V $_{\leq}$ V $_{CC}$ $_{\leq}$ 5.5 V and V $_{SS}$ = 0 V.
- $\underline{2}/$ Unless otherwise specified, the DC test conditions are as follows: Input pulse levels: V $_{IH}$ = V $_{CC}$ 0.3 V and V $_{IL}$ = 0.3 V.

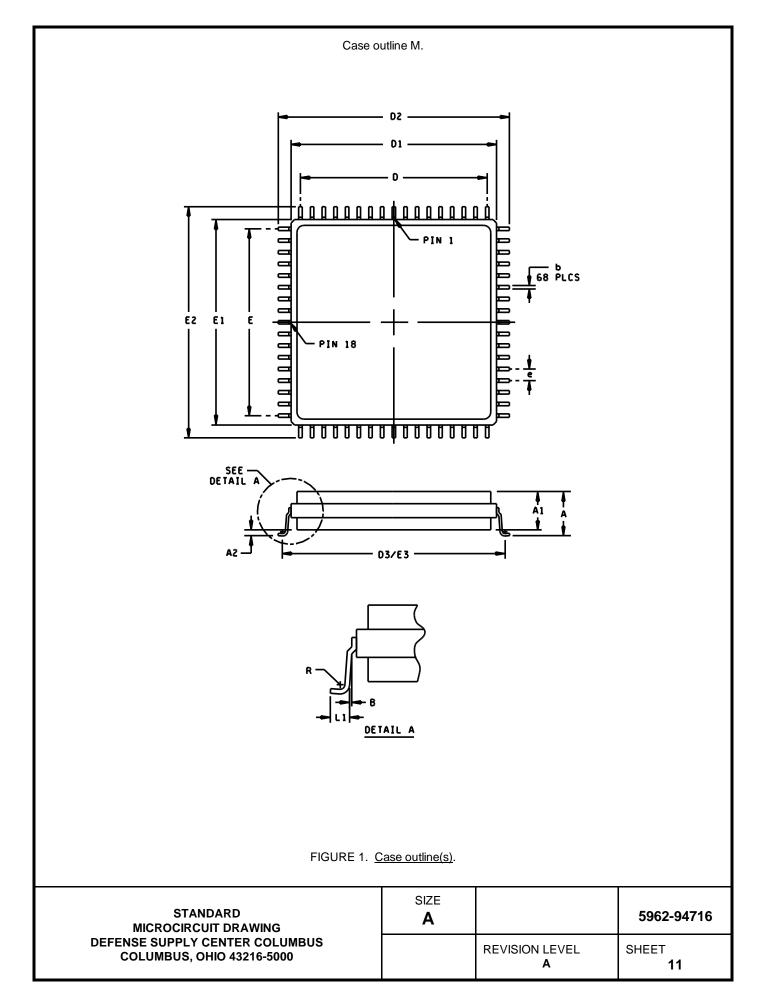
Unless otherwise specified, the AC test conditions are as follows: Input pulse Levels: $V_{IL}=0\ V$ and $V_{IH}=3.0\ V.$ Input rise and fall times: 5 nanoseconds. Input and output timing reference levels: 1.5 V.

Output load circuit as per figure 8.

3/ Guaranteed by design, but not tested.

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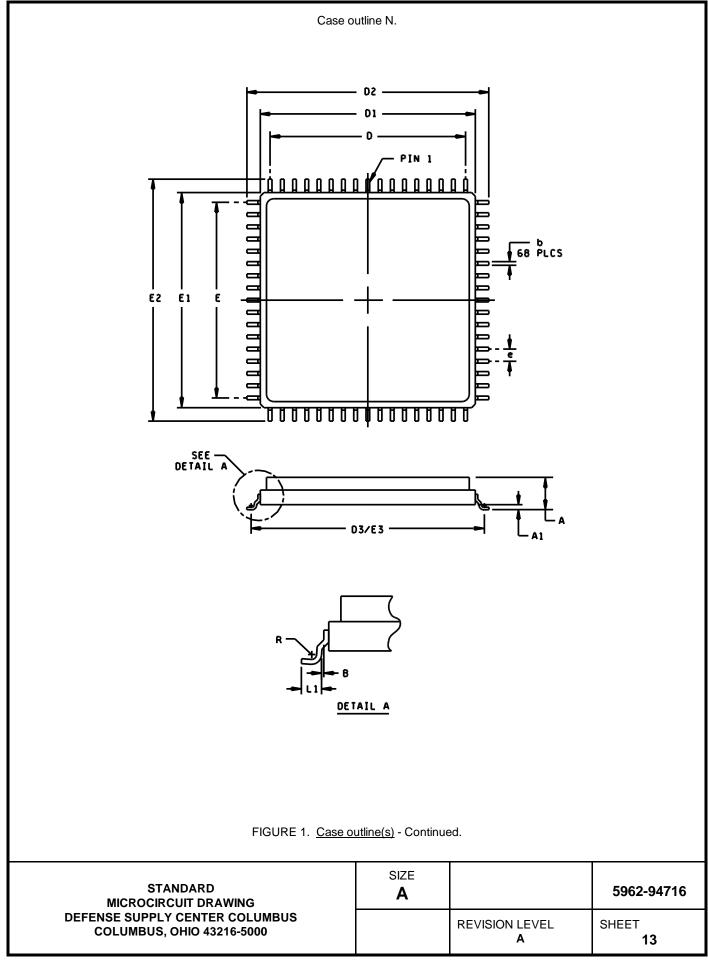


 Symbol	Millimeters		 Inc	hes	
<u> </u> 	Min	 Max	 Min	 Max	
 <u> </u>	4.01	 5.10	 0.158	 0.200	
 <u> </u>	3.91	 4.72	 0.154	 <u>0.186</u>	
 A2	0.24	 0.38	0.005	 0.015	
l b	0.33	0.43	0.013	 0.017	
l D/E	20.3 B	•	0.800 BSC		
D1/E1	22.10	 22.65	0.870		
D2/E2	24.89	25.35	0.980	1.000	
D3/E3	23.75	24.28	0.936	0.956	
<u> D3/L3</u> e	1.27 BSC		0.050 E	ĺ	
<u> </u>	0.13		0.030 L		
<u>K</u> <u>L</u> 1	0.13	1.14	0.005	0.045	

- The U.S. preferred system of measurement is the metric SI. This item was designed using inch-pound units of measurement. In case of problems involving conflicts between the metric and inch-pound units, the inch-pound units shall rule.
- 2. Pin numbers are for reference only.
- 3. Case outline M is a dual cavity package.

FIGURE 1. Case outline(s) - Continued.

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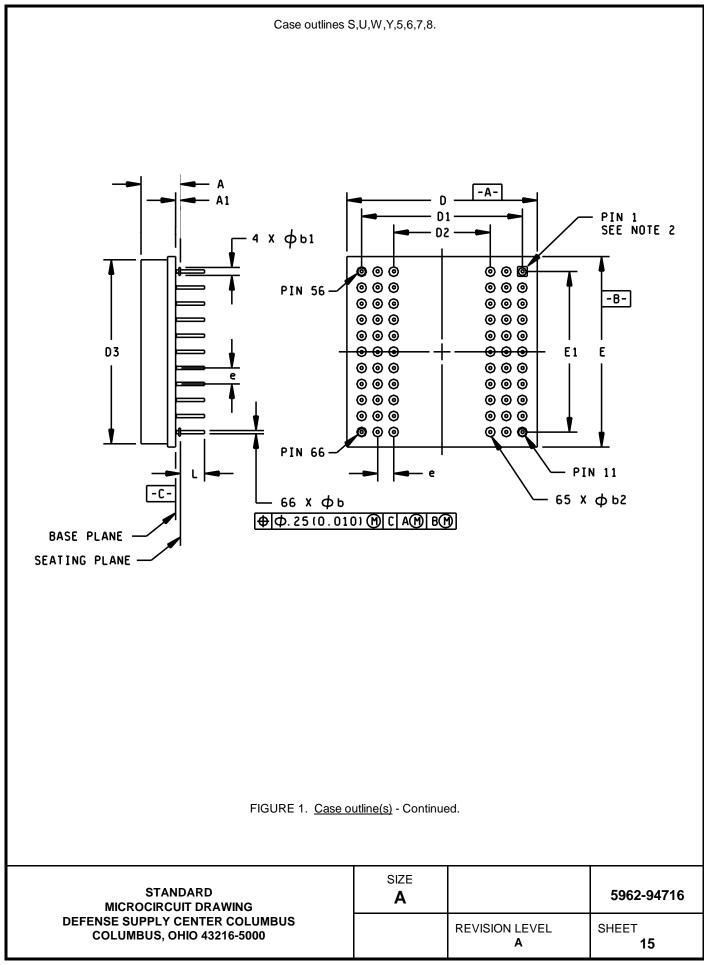


Symbol	Millim	eters	 Inc	hes	
 	 Min	 Min Max		 Max	
i A	3.12	4.06	0.123	0.160	
 A1	0.13	0.64	0.005	0.025	
/ / /	0.33	0.43	i i		
<u> </u>	0.33 0.43 20.3 BSC		0.800 BSC		
			İ		
<u>D1/E1</u> 	22.10	22.65 	0.870 	0.890 	
D2/E2 	24.89	<u>25.35</u> 	0.980 	1.000 	
D3/E3 	23.75	24.28	0.936 0.956		
<u> e </u>	1.27 BSC		0.050 BSC		
 <u>R</u>	0.25 TYP.		0.010 E	BSC	
l <u> </u>	0.89	l 1.14	0.035	0.045	

- The U.S. preferred system of measurement is the metric SI. This item was designed using inch-pound units of measurement. In case of problems involving conflicts between the metric and inch-pound units, the inch-pound units shall rule.
- 2. Pin numbers are for reference only.
- 3. Case outline N is a single cavity package.

FIGURE 1. Case outline(s) - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94716
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL A	SHEET 14



Case outlines S,U,W,Y, only.

Symbol	Millimeters		mbol Millimeters Ir		Inch	nes
	Min	Min Max		Max		
A	5.08	6.22	0.200	0.245		
A1	0.64	0.89	0.025	0.035		
øb	0.41	0.51	0.016	0.020		
øb1	1.14	1.40	0.045	0.055		
øb2	1.65	1.91	0.065	0.075		
D/E	29.72	30.48	1.170	1.200		
D1/E1	25.40 B	SC	1.000 BSC			
D2	15.24 B	SC	0.600 BSC			
D3	28.96			1.150		
e	2.54 BSC		0.100 E	BSC		
L	3.68	3.94	0.145	0.155		

- 1. The U.S. preferred system of measurement is the metric SI. This item was designed using inch-pound units of measurement. In case of problems involving conflicts between the metric and inch-pound units, the inch-pound units shall rule.
- 2. Pin 1 is identified by 0.070 square pad.
- 3. Pin numbers are for reference only.

FIGURE 1. Case outlines(s) - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94716
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43216-5000		A	16

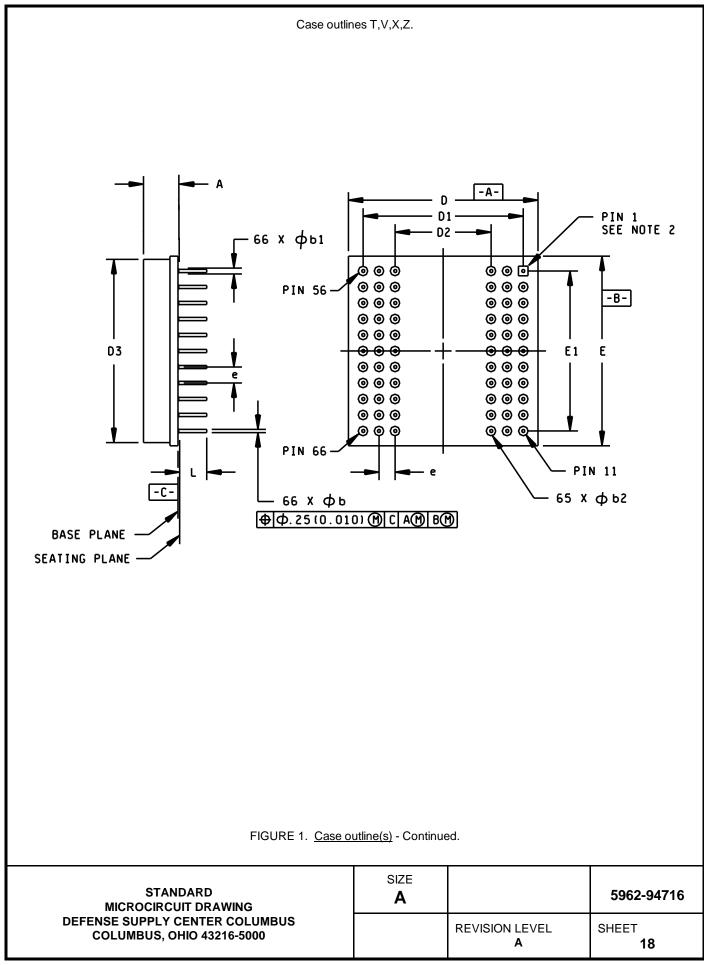
Case outlines 5,6,7,8, only.

Symbol	Millimeters		Incl	nes	
	Min	Min Max		Max	
A	4.60	4.34	0.156	0.181	
A1	0.64	0.89	0.025	0.035	
øb	0.41	0.51	0.016	0.020	
øb1	1.14	1.40	0.045	0.055	
øb2	1.65	1.91	0.065	0.075	
D/E	27.05	27.56	1.065	1.085	
D1/E1	25.40 B	SC	1.000 BSC		
D2	15.24 B	SC	0.600 BSC		
D3	26.16	26.42	1.030	1.040	
e	2.54 BSC		0.100 E	3SC	
L	3.68	3.94	0.145	0.155	

- 1. The U.S. preferred system of measurement is the metric SI. This item was designed using inch-pound units of measurement. In case of problems involving conflicts between the metric and inch-pound units, the inch-pound units shall rule.
- 2. Pin 1 is identified by 0.070 square pad.
- 3. Pin numbers are for reference only.

FIGURE 1. Case outlines(s) - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94716
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL A	SHEET 17



Case outlines T,V,X,Z - Continued.

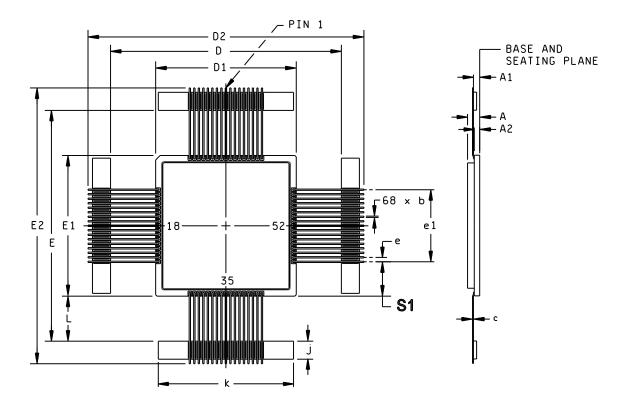
Symbol	Millimeters		ymbol Millimeters Inc		Inch	nes
	Min Max		Min	Max		
A	3.30	5.84	0.130	0.230		
øb	0.41	0.51	0.016	0.020		
øb1	0.76	Ref.	0.030 Ref.			
øb2	1.65	1.91	0.065	0.075		
D/E	26.92	30.48	1.060	1.200		
D1/E1	25.40 B	SC	1.000 BSC			
D2	15.24 B		0.600 BSC			
D3	26.16	29.21	1.030	1.150		
e	2.54 BSC		0.100 BSC			
L	4.19	4.69	0.165	0.185		

- The U.S. preferred system of measurement is the metric SI. This item was designed using inch-pound units of
 measurement. In case of problems involving conflicts between the metric and inch-pound units, the inch-pound units shall
 rule.
- 2. Pin 1 is identified by 0.070 square pad.
- 3. Pin numbers are for reference only.

FIGURE 1. Case outline(s) - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94716
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL A	SHEET 19





FI G URE 1. <u>Case outline(s)</u> - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94716
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL A	SHEET 20

				nes
Symbol	Millimeters		Incl	
				Max
	Min	Max	Min	
 <u> </u>	4.46	5.10	0.175	0.200
 <u> </u>	1.40	1.65	0.055	0.065
 <u>A2</u>	1.14	1.40	0.045	0.055
 <u> </u>	0.30	0.46	0.012	0.018
 <u> </u>	0.23	0.31	 0.009	0.012
 <u>D/E</u>	 63.63	 66.42	2.505	2.615
				1.575
<u>D1/E1</u>	39.24	40.01	1.545	
				3.315
<u>D2/E2</u>	73.28	84.20	2.885	
 <u> </u>	 1.14			0.055
				0.805
<u>e1</u>	20.19	20.45	0.795	
				0.210
j	4.83	5.33	0.190	
				1.515
<u> </u>	37.72	38.48	1.485	
				0.520
<u> L </u>	12.19	13.21	0.480	
 <u> </u>	9.45	 9.86	0.372	0.388

- 1. The U.S. preferred system of measurement is the metric SI. This item was designed using inch-pound units of measurement. In case of problems involving conflicts between the metric and inch-pound units, the inch-pound units shall rule.
- 2. Pin numbers are for reference only.

FIGURE 1. Case outline(s) - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94716
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL A	SHEET 21

Device types	All	Device types	All	Device types	All	Device types	All
Case outlines	M, N	Case outlines	M, N	Case outlines	M, N	Case outlines	M, N
Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol
1	GND	18	GND	35	OE	52	GND
2	CS3	19	I/O8	36	CS2	53	I/O23
3	A5	20	I/O9	37	NC	54	I/O22
4	A4	21	I/O10	38	WE2	55	I/O21
5	А3	22	I/O11	39	WE3	56	I/O20
6	A2	23	I/O12	40	WE4	57	I/O19
7	A1	24	I/O13	41	NC	58	I/O18
8	A0	25	I/O14	42	NC	59	I/O17
9	NC	26	I/O15	43	NC	60	I/O16
10	I/O0	27	V _{CC}	44	I/O31	61	V _{CC}
11	I/O1	28	A11	45	I/O30	62	A10
12	I/O2	29	A12	46	I/O29	63	A9
13	I/O3	30	A13	47	I/O28	64	A8
14	I/O4	31	A14	48	1/027	65	A7
15	I/O5	32	A15	49	I/O26	66	A6
16	I/O6	33	A16	50	I/O25	67	WE1
17	I/O7	34	CS1	51	1/024	68	CS4

FIGURE 2. <u>Terminal connections</u>.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94716
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL A	SHEET 22

Device type	All	Device type	All	Device type	All	Device type	All
Case outlines	U,V,Y,Z, 6,8	Case outlines	U,V,Y,Z, 6,8	Case outlines	U,V,Y,Z, 6,8	Case outlines	U,V,Y,Z, 6,8
Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol
1	I/O8	18	A15	35	I/O25	52	WE3
2	I/O9	19	v _{cc}	36	I/O26	53	CS3
3	I/O10	20	CS1	37	A7	54	GND
4	A14	21	NC	38	A12	55	I/O19
5	A16	22	1/03	39	NC	56	I/O31
6	A11	23	I/015	40	A13	57	I/O30
7	A0	24	I/O14	41	A8	58	I/O29
8	NC	25	I/O13	42	I/O16	59	I/O28
9	I/O0	26	I/O12	43	I/O17	60	A1
10	I/O1	27	OE	44	I/O18	61	A2
11	I/O2	28	NC	45	V _{CC}	62	А3
12	WE2	29	WE1	46	 CS4	63	I/O23
13	CS2	30	1/07	47	WE4	64	I/O22
14	GND	31	I/O6	48	1/027	65	I/O21
15	I/O11	32	I/O5	49	A4	66	I/O20
16	A10	33	1/04	50	A5		
17	A9	34	I/O24	51	A6		

NOTE: Case outlines Y, Z, and 8, pins 8, 21, 28, and 39 are no connects (NC) and for case outlines U, V, and 6, pins 8, 21, 28, and 39 are ground.

FIGURE 2. <u>Terminal connections (industrial pin-outs)</u> - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94716
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL A	SHEET 23

Device type	All	Device type	All	Device type	All	Device type	All
Case outlines	S,T,W,X, 5,7	Case outlines	S,T,W,X, 5,7	Case outlines	S,T,W,X, 5,7	Case outlines	S,T,W,X, 5,7
Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol
1	I/O8	18	A12	35	I/O25	52	WE3
2	I/O9	19	V _{CC}	36	I/O26	53	CS3
3	I/O10	20	<u></u> CS1	37	A6	54	GND
4	A13	21	NC	38	A7	55	I/O19
5	A14	22	1/03	39	NC	56	I/O31
6	A15	23	I/015	40	A8	57	I/O30
7	A16	24	I/O14	41	A9	58	I/O29
8	NC	25	I/O13	42	I/O16	59	I/O28
9	I/O0	26	I/O12	43	I/O17	60	A0
10	I/O1	27	OE	44	I/O18	61	A1
11	I/O2	28	NC	45	V _{CC}	62	A2
12	WE2	29	WE1	46	 CS4	63	I/O23
13	CS2	30	I/O7	47	WE4	64	I/O22
14	GND	31	I/O6	48	1/027	65	I/O21
15	I/O11	32	I/O5	49	А3	66	I/O20
16	A10	33	I/O4	50	A4		
17	A11	34	I/O24	51	A5		

NOTE: Case outlines W, X, and 7, pins 8, 21, 28, and 39 are no connects (NC) and for case outlines S, T, and 5, pins 8, 21, 28, and 39 are ground.

FIGURE 2. <u>Terminal connections (alternative pin-outs)</u> - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94716
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL A	SHEET 24

Device types	All	Device types	All	Device types	All	Device types	All
Case outline	4	Case outline	4	Case outline	4	Case outline	4
Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol
1	GND	18	GND	35	ŌĒ	52	GND
2	CS1	19	I/O8	36	CS4	53	I/O23
3	A5	20	I/O9	37	NC	54	I/O22
4	A4	21	I/O10	38	NC	55	I/O21
5	А3	22	I/O11	39	NC	56	I/O20
6	A2	23	I/O12	40	NC	57	I/O19
7	A1	24	I/O13	41	NC	58	I/O18
8	A0	25	I/O14	42	NC	59	I/O17
9	NC	26	I/O15	43	NC	60	I/O16
10	I/O0	27	V _{CC}	44	I/O31	61	V _{CC}
11	I/O1	28	A11	45	I/O30	62	A10
12	I/O2	29	A12	46	I/O29	63	A9
13	I/O3	3	A13	47	I/O28	64	A8
14	I/O4	31	A14	48	1/027	65	A7
15	I/O5	32	A15	49	I/O26	66	A6
16	I/O6	33	A16	50	I/O25	67	WE
17	I/O7	34	CS2	51	I/O24	68	CS3

FIGURE 2. <u>Terminal connections</u> - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94716
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL A	SHEET 25

_	l OE	WE	Data I/O	MODE	Device Current
Н	Х	Х	High Z	Standby	Standby
L	L	Н	Data out	Read	Active
L	Н	L	Data in	Write	Active

- H = V_{IH} = High Logic Level
 L = V_{IL} = Low Logic Level
 X = Do not care (either high or low)
 High Z = High Impedance State

FIGURE 3. Truth table.

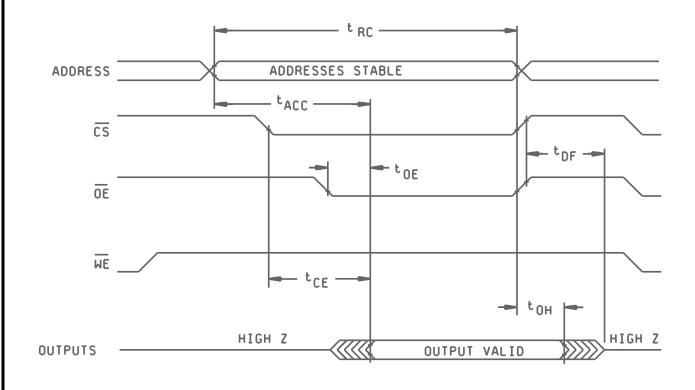


FIGURE 4. Read cycle timing diagram.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000	SIZE A		5962-94716
		REVISION LEVEL A	SHEET 26

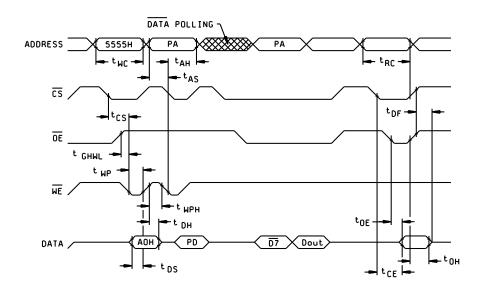
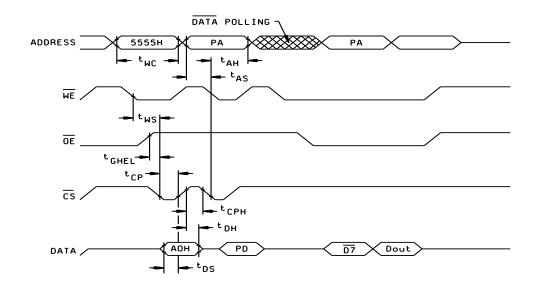


FIGURE 5. Write/Erase/Program Operations, WE controlled.

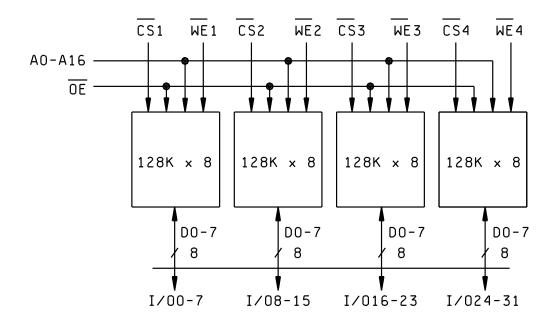


- 1. PA represents the address of the memory location to be programmed.
- 2. PD represents the data to be programmed at byte address.
- 3. D7 is the output of the complement of the data written to the device.
- 4. DOUT is the output of the data written to the device.
- 5. Figures indicate last two bus cycles of a four bus cycle sequence.

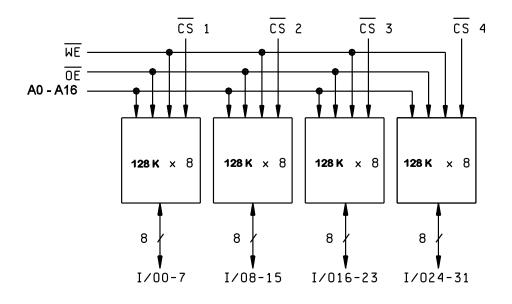
FIGURE 6. Write/Erase/Operations, CS controlled.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000	SIZE A		5962-94716
		REVISION LEVEL A	SHEET 27

Case outlines M, N, S, T, U, V, W, X, Y, Z, 5, 6, 7, and 8.



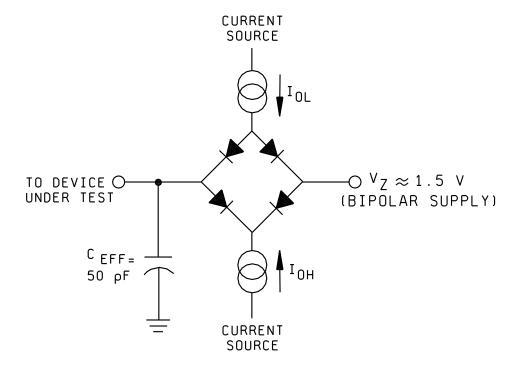
Case outline 4.



RE 7. Block diagram(s).

FIGU

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000	SIZE A		5962-94716
		REVISION LEVEL A	SHEET 28



- 1. V₇ is programmable from -2 V to +7 V.
- I_{OL} & I_{OH} are programmable from 0 to 16 mA.
 Tester impedance (Z0) = 75 ohms.

- V_Z is typically the midpoint of V_{OH} and V_{OL}.
 I_{OL} & I_{OH} are adjusted to simulate a typical resistive load circuit.
 ATE tester includes jig capacitance.

FIGURE 8. Output test circuit.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000	SIZE A		5962-94716
		REVISION LEVEL A	SHEET 29

TABLE II. Electrical test requirements.

MIL-PRF-38534 test requirements	Subgroups (in accordance with MIL-PRF-38534,group A test table)
Interim electrical parameters	1,4,7,9
Final electrical test parameters	1*,2,3,4,7,8A,8B,9,10,11
Group A test requirements	1,2,3,4,7,8A,8B,9,10,11
Group C end-point electrical parameters	1,2,3,4,7,8A,8B,9,10,11
MIL-STD-883, group E end-point electrical parameters for RHA devices	Subgroups ** (in accordance with method 5005, group A test table)

^{*} PDA applies to subgroup 1.

- 4.2 <u>Screening</u>. Screening shall be in accordance with MIL-PRF-38534, or by the manufacturer's Quality Management (QM) Plan in accordance with appendix B of MIL-PRF-38534. The following additional criteria shall apply:
 - a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition B. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to either DSCC-VA or the acquiring activity upon request. Also, the test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
 - (2) T_A as specified in accordance with table I of method 1015 of MIL-STD-883.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 <u>Conformance and periodic inspections</u>. Conformance inspection (CI) and periodic inspection (PI) shall be in accordance with MIL-PRF-38534 and as specified herein.

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		REVISION LEVEL A	SHEET 30

^{**} When applicable to this standard microcircuit drawing, the subgroups shall be defined.

- 4.3.1 Group A inspection (CI). Group A inspection shall be in accordance with MIL-PRF-38534 and as follows:
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 5 and 6 shall be omitted.
 - c. Subgroups 7, 8A, and 8B shall include verification of the truth table.
 - d. The following data patterns shall be verified during subgroups 7, 8A, and 8B:
 - (1) 0's to all memory cell locations.
 - (2) Checkerboard pattern to entire memory array.
 - (3) Checkerboard compliment to entire memory array.
- 4.3.2 Group B inspection (PI). Group B inspection shall be in accordance with MIL-PRF-38534.
- 4.3.3 Group C inspection (PI). Group C inspection shall be in accordance with MIL-PRF-38534 and as follows:
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test, method 1005 of MIL-STD-883.
 - (1) Test condition B. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to either DSCC-VA or the acquiring activity upon request. Also, the test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.
 - (2) T_A as specified in accordance with table I of method 1005 of MIL-STD-883.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.
 - (4) The checkerboard data pattern shall be verified after burn-in as part of end-point electrical testing.
- 4.3.4 Group D inspection (PI). Group D inspection shall be in accordance with MIL-PRF-38534.
- 4.3.5 <u>Group E inspection</u>. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein). RHA levels for device classes H and K shall be M, D, R, and H. RHA quality conformance inspection sample tests shall be performed at the RHA level specified in the acquisition document.
 - a. RHA tests for device classes H and K for levels M, D, R, and H shall be performed through each level to determine at what levels the devices meet the RHA requirements. These RHA tests shall be performed for initial qualification and after design or process changes which may affect the RHA performance of the device.
 - b. End-point electrical parameters shall be as specified in table II herein.
 - c. Prior to total dose irradiation, each selected sample shall be assembled in its qualified package. It shall pass the specified group A electrical parameters in table I for subgroups specified in table II herein.
 - d. For device classes H and K, the devices shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38534 for RHA level being tested, and meet the postirradiation end-point electrical parameter limits as defined in table I at $T_A = +25^{\circ}\text{C}$ ±5 percent, after exposure.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-94716
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL A	SHEET 31

- e. Prior to and during total dose irradiation testing, the devices shall be biased to establish a worst case condition as specified in the radiation exposure circuit.
- f. For device classes H and K, subgroups 1 and 2 in table V, method 5005 of MIL-STD-883 shall be tested as appropriate for device construction.
- g. When specified in the purchase order or contract, a copy of the RHA delta limits shall be supplied.
- 5. PACKAGING
- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38534.
- 6. NOTES
- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-973 using DD Form 1692, Engineering Change Proposal.
- 6.4 <u>Record of users</u>. Military and industrial users shall inform Defense Supply Center Columbus when a system application requires configuration control and the applicable SMD. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-7603.
- 6.5 <u>Comments</u>. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43216-5000, or telephone (614) 692-0676.
- 6.6 <u>Sources of supply for device classes H and K.</u> Sources of supply for device classes H and K are listed in QML-38534. The vendors listed in QML-38534 have submitted a certificate of compliance (see 3.7 herein) to DSCC-VA and have agreed to this drawing.

STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000	SIZE A		5962-94716
		REVISION LEVEL A	SHEET 32

STANDARD MICROCIRCUIT DRAWING SOURCE APPROVAL BULLETIN

DATE: 96-08-30

Approved sources of supply for SMD 5962-94716 are listed below for immediate acquisition only and shall be added to QML-38534 during the next revision. QML-38534 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This bulletin is superseded by the next dated revision of QML-38534.

	li	
Standard	Vendor	Vendor
microcircuit	CAGE	similar
drawing PIN 1/	number	PIN 2/
urawing File <u>i/</u>	Humber	1 IIV <u>2</u> /
5962-9471601HMA	54230	WF128K32-150G2Q5
5962-9471601HMC	54230	WF128K32-150G2Q5
5962-9471601HNA	88379	ACT-F128K32N-150F5Q
5962-9471601HNC	88379	ACT-F128K32N-150F5Q
5962-9471601HSA	54230	WF128K32A-150HQ5
5962-9471601HSC	54230	WF128K32A-150HQ5
5962-9471601HTA	54230	WF128K32A-150HSQ5
5962-9471601HTC	54230	WF128K32A-150HSQ5
5962-9471601HUA	54230	WF128K32-150HQ5
5962-9471601HUC	54230	WF128K32-150HQ5
5962-9471601HVA	54230	WF128K32-150HSQ5
5962-9471601HVC	54230	WF128K32-150HSQ5
5962-9471601HWA	54230	WF128K32NA-150HQ5
5962-9471601HWC	54230	WF128K32NA-150HQ5
5962-9471601HXA	54230	WF128K32NA-150HSQ5
5962-9471601HXC	54230	WF128K32NA-150HSQ5
5962-9471601HYA	54230	WF128K32N-150HQ5
5962-9471601HYC	54230	WF128K32N-150HQ5
5962-9471601HZA	54230	WF128K32N-150HSQ5
5962-9471601HZC	54230	WF128K32N-150HSQ5
5962-9471601HZA	88379	ACT-F128K32N-150P3Q
5962-9471601HZC	88379	ACT-F128K32N-150P3Q
5962-9471601H4C	54230	WF128K32-150G4Q5
5962-9471601H5A	54230	WF128K32A-150H1Q5
5962-9471601H5C	54230	WF128K32A-150H1Q5
5962-9471601H6A	54230	WF128K32-150H1Q5
5962-9471601H6C	54230	WF128K32-150H1Q5
5962-9471601H7A	54230	WF128K32NA-150H1Q5
5962-9471601H7C	54230	WF128K32NA-150H1Q5
5962-9471601H8A	54230	WF128K32N-150H1Q5
5962-9471601H8C	54230	WF128K32N-150H1Q5
5962-9471601H8A	88379	ACT-F128K32N-150P7Q
5962-9471601H8C	88379	ACT-F128K32N-150P7Q

	1	
Standard	Vendor	Vendor
microcircuit	CAGE	similar
drawing PIN 1/	number	PIN 2/
5962-9471602HMA	54230	WF128K32-120G2Q5
5962-9471602HMC	54230	WF128K32-120G2Q5
5962-9471602HNA	88379	ACT-F128K32N-120F5Q
5962-9471602HNC	88379	ACT-F128K32N-120F5Q
5962-9471602HSA	54230	WF128K32A-120HQ5
5962-9471602HSC	54230	WF128K32A-120HQ5
5962-9471602HTA	54230	WF128K32A-120HSQ5
5962-9471602HTC	54230	WF128K32A-120HSQ5
5962-9471602HUA	54230	WF128K32-120HQ5
5962-9471602HUC	54230	WF128K32-120HQ5
5962-9471602HVA	54230	WF128K32-120HSQ5
5962-9471602HVC	54230	WF128K32-120HSQ5
5962-9471602HWA	54230	WF128K32NA-120HQ5
5962-9471602HWC	54230	WF128K32NA-120HQ5
5962-9471602HXA	54230	WF128K32NA-120HSQ5
5962-9471602HXC	54230	WF128K32NA-120HSQ5
5962-9471602HYA	54230	WF128K32N-120HQ5
5962-9471602HYC	54230	WF128K32N-120HQ5
5962-9471602HZA	54230	WF128K32N-120HSQ5
5962-9471602HZC	54230	WF128K32N-120HSQ5
5962-9471602HZA	88379	ACT-F128K32N-120P3Q
5962-9471602HZC	88379	ACT-F128K32N-120P3Q
5962-9471602H4C	54230	WF128K32-120G4Q5
5962-9471602H5A	54230	WF128K32A-120H1Q5
5962-9471602H5C	54230	WF128K32A-120H1Q5
5962-9471602H6A	54230	WF128K32-120H1Q5
5962-9471602H6C	54230	WF128K32-120H1Q5
5962-9471602H7A	54230	WF128K32NA-120H1Q5
5962-9471602H7C	54230	WF128K32NA-120H1Q5
5962-9471602H8A	54230	WF128K32N-120H1Q5
5962-9471602H8C	54230	WF128K32N-120H1Q5
5962-9471602H8A	88379	ACT-F128K32N-120P7Q
5962-9471602H8C	88379	ACT-F128K32N-120P7Q

	1	1
Standard	Vendor	Vendor
microcircuit	CAGE	similar
drawing PIN 1/	number	PIN 2/
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5962-9471603HMA	54230	WF128K32-90G2Q5
5962-9471603HMC	54230	WF128K32-90G2Q5
5962-9471603HNA	88379	ACT-F128K32N-090F5Q
5962-9471603HNC	88379	ACT-F128K32N-090F5Q
5962-9471603HSA	54230	WF128K32A-90HQ5
5962-9471603HSC	54230	WF128K32A-90HQ5
5962-9471603HTA	54230	WF128K32A-90HSQ5
5962-9471603HTC	54230	WF128K32A-90HSQ5
5962-9471603HUA	54230	WF128K32-90HQ5
5962-9471603HUC	54230	WF128K32-90HQ5
5962-9471603HVA	54230	WF128K32-90HSQ5
5962-9471603HVC	54230	WF128K32-90HSQ5
5962-9471603HWA	54230	WF128K32NA-90HQ5
5962-9471603HWC	54230	WF128K32NA-90HQ5
5962-9471603HXA	54230	WF128K32NA-90HSQ5
5962-9471603HXC	54230	WF128K32NA-90HSQ5
5962-9471603HYA	54230	WF128K32N-90HQ5
5962-9471603HYC	54230	WF128K32N-90HQ5
5962-9471603HZA	54230	WF128K32N-90HSQ5
5962-9471603HZC	54230	WF128K32N-90HSQ5
5962-9471603HZA	88379	ACT-F128K32N-090P3Q
5962-9471603HZC	88379	ACT-F128K32N-090P3Q
5962-9471603H4C	54230	WF128K32-90G4Q5
5962-9471603H5A	54230	WF128K32A-90H1Q5
5962-9471603H5C	54230	WF128K32A-90H1Q5
5962-9471603H6A	54230	WF128K32-90H1Q5
5962-9471603H6C	54230	WF128K32-90H1Q5
5962-9471603H7A	54230	WF128K32NA-90H1Q5
5962-9471603H7C	54230	WF128K32NA-90H1Q5
5962-9471603H8A	54230	WF128K32N-90H1Q5
5962-9471603H8C	54230	WF128K32N-90H1Q5
5962-9471603H8A	88379	ACT-F128K32N-090P7Q
5962-9471603H8C	88379	ACT-F128K32N-090P7Q

STANDARD MICROCIRCUIT DRAWING SOURCE APPROVAL BULLETIN - Continued.

1	I	1
Standard	Vendor	Vendor
microcircuit	CAGE	similar
drawing PIN 1/	number	PIN 2/
arawing r ii v <u>ir</u>	Hamboi	1 "
5962-9471604HMA	54230	WF128K32-70G2Q5
5962-9471604HMC	54230	WF128K32-70G2Q5
5962-9471604HNA	88379	ACT-F128K32N-070F5Q
5962-9471604HNC	88379	ACT-F128K32N-070F5Q
5962-9471604HSA	54230	WF128K32A-70HQ5
5962-9471604HSC	54230	WF128K32A-70HQ5
5962-9471604HTA	54230	WF128K32A-70HSQ5
5962-9471604HTC	54230	WF128K32A-70HSQ5
5962-9471604HUA	54230	WF128K32-70HQ5
5962-9471604HUC	54230	WF128K32-70HQ5
5962-9471604HVA	54230	WF128K32-70HSQ5
5962-9471604HVC	54230	WF128K32-70HSQ5
5962-9471604HWA	54230	WF128K32NA-70HQ5
5962-9471604HWC	54230	WF128K32NA-70HQ5
5962-9471604HXA	54230	WF128K32NA-70HSQ5
5962-9471604HXC	54230	WF128K32NA-70HSQ5
5962-9471604HYA	54230	WF128K32N-70HQ5
5962-9471604HYC	54230	WF128K32N-70HQ5
5962-9471604HZA	54230	WF128K32N-70HSQ5
5962-9471604HZC	54230	WF128K32N-70HSQ5
5962-9471604HZA	88379	ACT-F128K32N-070P3Q
5962-9471604HZC	88379	ACT-F128K32N-070P3Q
5962-9471604H4C	54230	WF128K32-70G4Q5
5962-9471604H5A	54230	WF128K32A-70H1Q5
5962-9471604H5C	54230	WF128K32A-70H1Q5
5962-9471604H6A	54230	WF128K32-70H1Q5
5962-9471604H6C	54230	WF128K32-70H1Q5
5962-9471604H7A	54230	WF128K32NA-70H1Q5
5962-9471604H7C	54230	WF128K32NA-70H1Q5
5962-9471604H8A	54230	WF128K32N-70H1Q5
5962-9471604H8C	54230	WF128K32N-70H1Q5
5962-9471604H8A	88379	ACT-F128K32N-070P7Q
5962-9471604H8C	88379	ACT-F128K32N-070P7Q

STANDARD MICROCIRCUIT DRAWING SOURCE APPROVAL BULLETIN - Continued.

	1	T
Standard	Vendor	Vendor
microcircuit	CAGE	similar
drawing PIN <u>1</u> /	number	PIN <u>2</u> /
5962-9471605HMA 5962-9471605HMC 5962-9471605HSA 5962-9471605HSC 5962-9471605HTA 5962-9471605HTC 5962-9471605HUC 5962-9471605HUC 5962-9471605HVC 5962-9471605HVC 5962-9471605HWC 5962-9471605HXA 5962-9471605HXC 5962-9471605HXC 5962-9471605HYC 5962-9471605HZC 5962-9471605HZC 5962-9471605HZC 5962-9471605HZC 5962-9471605HZC 5962-9471605HZC 5962-9471605HZC 5962-9471605H3C 5962-9471605H3C	54230 54230	WF128K32-60G2Q5 WF128K32-60G2Q5 WF128K32A-60HQ5 WF128K32A-60HQ5 WF128K32A-60HSQ5 WF128K32-60HQ5 WF128K32-60HQ5 WF128K32-60HQ5 WF128K32-60HQ5 WF128K32-60HSQ5 WF128K32NA-60HQ5 WF128K32NA-60HQ5 WF128K32NA-60HQ5 WF128K32NA-60HQ5 WF128K32NA-60HSQ5 WF128K32NA-60HSQ5 WF128K32NA-60HQ5
5962-9471605H6A	54230	WF128K32-60H1Q5
5962-9471605H6C	54230	WF128K32-60H1Q5
5962-9471605H7A	54230	WF128K32NA-60H1Q5
5962-9471605H7C	54230	WF128K32NA-60H1Q5
5962-9471605H8A	54230	WF128K32N-60H1Q5
5962-9471605H8C	54230	WF128K32N-60H1Q5

^{1/} The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. The device manufacturers listed herein are authorized to supply alternate lead finishes "A", "B", or "C" at their discretion. Contact the listed approved source of supply for further information.

^{2/} Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

STANDARD MICROCIRCUIT DRAWING SOURCE APPROVAL BULLETIN - Continued.

DATE: 96-08-30

Vendor CAGE <u>number</u>	Vendor name <u>and address</u>
54230	White Microelectronics 4246 East Wood Street Phoenix, AZ 85040-1991
88379	Aeroflex Circuit Technology Corporation 35 South Service Road Plainview, NY 11803

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